

## SAM<sup>TM</sup> Data Sheet SAM-1064-39-6ps-x, $\lambda$ = 1064 nm

Laser wavelength  $\lambda = 1064 \text{ nm}$ 

High reflection band  $\lambda = 1000 ... 1100 \text{ nm}$ 

Absorptance  $A_0 = 39 \%$  Modulation depth  $\Delta R = 24 \%$  Non-saturable loss  $A_{ns} = 15 \%$  Saturation fluence  $\Phi_{sat} = 40 \ \mu J/cm^2$ 

Relaxation time constant  $\tau = 6 \text{ ps}$ 

Damage threshold  $\Phi = 1.5 \text{ mJ/cm}^2$ 

Chip area 4.0 mm x 4.0 mm; other dimensions on request

Chip thickness 450 µm

Protection the SAM is protected with a dielectric front layer

Mounting option **x** denotes the type of mounting as follows:

x = 0 unmounted

x = 12.7 g glued on a gold plated Cu-cylinder with 12.7 mm Ø
x = 25.4 g glued on a gold plated Cu-cylinder with 25.4 mm Ø
x = 12.7 s soldered on a gold plated Cu-cylinder with 12.7 mm Ø
x = 25.4 s soldered on a gold plated Cu-cylinder with 25.4 mm Ø
x = FC mounted on a 1 m monomode fiber cable with FC connector

## Low intensity spectral reflectance

